

1703 E. Highway 50 Yankton, SD 57078 USA

Phone: 800-762-8800 or 605-665-9321 Fax: 605-665-1709

Website: www.mtronpti.com



SPECIFICATION FOR SMT VCTCXO MtronPTI P/N: M6054S031

Electrical Specifications:

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions		
Frequency of Operation	Fo		13.00000		MHz			
Frequency Tolerance				±1	ppm	@ 25°C, at time of shipping		
		F	requency Sta	bility				
Frequency Stability	ΔF/F			±5.0	ppm			
Frequency Vs. Supply	$\Delta F_{VDD}/F$			±0.2	ppm	For ±5% voltage change		
Frequency Vs. Output Load				±0.2	ppm	For ±10% output load change		
Frequency Vs. Aging				±1.0	ppm	Per year		
			Output					
Output Type		Clipped Sinewave						
Output Load		10kΩ 10pF						
Output Level		0.8			V	pk-pk		
Startup Time	Tsu			2	mS			
			Voltage Tuni	ng				
Tuning Voltage		0.50	1.50	2.50	V	Pad 1		
Tuning Range		-8		+8	ppm	Ref. to frequency with Vc=1.50		
Input Impedance	Z _{IN}	100			ΚΩ			
Supply Voltage & Power Consumption								
Operating Voltage	V_{DD}	2.8	3.0	3.3	V			
Operating Current	I _{DD}			1.5	mA			

Environmental Conditions:

Operating Temperature	T _A	-40		+85	°C	
Storage Temperature	Ts	-40		+85	°C	
Mechanical Shock	Per MIL-STE	Per MIL-STD-202, Method 213 (2000 g, 0.3 ms duration, ½ sine wave)				
Vibration	Per MIL-STE	Per MIL-STD-202, Method 201 & 204 (10 g's from 10-2000 Hz)				
Hermeticity	Per MIL-STE	Per MIL-STD-202, Method 112 (1x10-8 atm.cc/s of helium)				
Solderability	Per EIAJ-ST	Per EIAJ-STD-002				
Max. Soldering Conditions	See solder profile, Figure 1					
Package Type	5.0 x 3.2 x 1.1 mm, Ceramic Leadless Chip Carrier (M6054 Series)					



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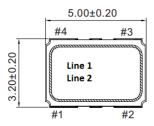
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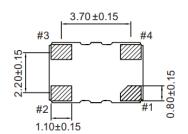
Mechanical, Marking and Layout Information:

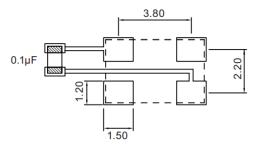
Part Marking			
Line 1	13M000		
Line 2	• M yy ww vv		

Legend				
уу	Last 2 digits of year			
ww	Week number			
vv	Factory Code			
•	Pin 1 Indicator			

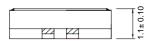
Pad	Function
1	Tuning Voltage
2	GND
3	Output
4	+V _{DD}







For optimal performance, place a 0.1uF bypass capacitor as close to Vdd and GND as possible



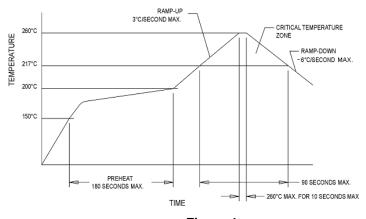


Figure 1

Datasheet Revision Table:

Date	Rev.	Author	Details of Revision
11-01-19	Α	BRR	Original Release.